

CLAIMS

What is claimed is:

- 1 1. A method of storing objects in a nonvolatile memory comprising:
2 allocating space within a block erasable nonvolatile memory for an object,
3 wherein the allocated space is within a single block;
4 storing a first instance of the object within the allocated space; and
5 storing a superseding second instance of the object within the allocated space
6 without erasing any of the allocated space, wherein each instance of the object is a fixed
7 size, wherein the allocated space exceeds a multiple of the fixed size.
- 1 2. The method of claim 1, further comprising:
2 updating status information within the allocated space to reflect that the second
3 instance supersedes the first instance.
- 1 3. The method of claim 1, further comprising:
2 storing a header within a same block as the allocated space, wherein the header
3 identifies a location of the allocated space within the same block.
- 1 4. The method of claim 1, wherein the nonvolatile memory is a flash electrically
2 erasable programmable read only memory.
- 1 5. A method comprising:
2 receiving data for storage in a nonvolatile memory comprising a plurality of
3 blocks;

4 selecting a storage structure for the data according to a size (z) of the data, a
 5 minimum number of instances (m), a maximum single instance size ($s*g$), and an
 6 allocation granularity (g);
 7 storing the data in the selected structure within the nonvolatile memory.

1 6. The method of claim 5, wherein selecting the storage structure includes selecting a
 2 multiple instance structure, if $z \leq \frac{g - \text{overhead}}{m}$, wherein the overhead is an amount
 3 of space required as overhead for m instances within the multiple instance structure.

1 7. The method of claim 5, wherein selecting the storage structure further includes
 2 selecting a single instance structure, if $z \leq s*g$ for s expressed as a number of granular
 3 units.

1 8. The method of claim 5, wherein selecting the storage structure further includes
 2 fragmenting the data into a plurality of data fragments for storage, if $z > s*g$ for s
 3 expressed as a number of granular units.

1 9. The method of claim 8, wherein storing the data includes:
 2 storing the data fragments using a sequence table indicative of an order and a location of
 3 the data fragments, if a sequence table size does not exceed a maximum sequence table
 4 size; and
 5 storing a header for each data fragment and the sequence table, wherein the header
 6 is located in a same block as its associated data fragment and sequence table, wherein
 7 within a given block the headers are stored contiguously proceeding from a first end to a

8 second end of the given block, wherein objects identified by the headers are stored
9 contiguously proceeding from the second end to a first end of the given block.

1 10. The method of claim 8, wherein storing the data further includes:

2 storing the data fragments using sequence table fragments and a group table, if a
3 sequence table size exceeds the maximum sequence table size, wherein the sequence
4 table fragments are indicative of an order and a location of the data fragments, wherein
5 the group table is indicative of an order and a location of the sequence table fragments;

6 and

7 storing a header for each data fragment, sequence table fragment, and group table,
8 wherein the header is located in a same block as its associated data fragment, sequence
9 table fragment, and group table, wherein within a given block the headers are stored
10 contiguously proceeding from a first end to a second end of the given block, wherein
11 objects identified by the headers are stored contiguously proceeding from the second end
12 to a first end of the given block.

1 11. A method for a memory device comprising:

2 duplicating a power-loss recovery (PLR) status field such that the duplicated PLR
3 status field is used if the PLR status field is invalid.

1 12. The method of claim 11, wherein duplicating the PLR status field includes:

2 writing a same value in the PLR status field in the duplicated PLR status field.

1 13. The method of claim 12, wherein writing the same value includes writing the
2 same value in the PLR status filed in the duplicated PLR status field in a subsequent bus
3 cycle.

1 14. The method of claim 11, further comprising:
2 determining which of the PLR status field or the duplicated PLR status field
3 contains a greater amount of "1" bits for use in a power-loss recovery operation.

1 15. The method of claim 11, wherein duplicating the power-loss recovery (PLR)
2 status field includes duplicating the power-loss recovery (PLR) status field a flash
3 memory device.

0 1 2 3 4 5 6 7 8 9 10 11 12 13 14 15 16 17 18 19 20 21 22 23 24 25 26 27 28 29 30 31 32 33 34 35 36 37 38 39 40 41 42 43 44 45 46 47 48 49 50 51 52 53 54 55 56 57 58 59 60 61 62 63 64 65 66 67 68 69 70 71 72 73 74 75 76 77 78 79 80 81 82 83 84 85 86 87 88 89 90 91 92 93 94 95 96 97 98 99